## 74CB3Q3253

# Dual 1-of-4 FET multiplexer/demultiplexer with charge pump Rev. 2 — 28 June 2021 Product data sheet

### 1. General description

The 74CB3Q3253 is a dual high-bandwidth single-pole, quad-throw FET bus switch. Each switch features a select input (Sn) and an output enable input ( $\overline{\text{nOE}}$ ). The switch is disabled when the  $\overline{\text{nOE}}$  input is HIGH. An internal charge-pump increases the gate voltage of the NMOS pass transistor. The result is improved R<sub>ON</sub> and R<sub>ON(flat)</sub> performance and the ability to switch 5 V signals when V<sub>CC</sub> = 3.3 V.

#### 2. Features and benefits

- Wide supply voltage range from 2.3 V to 3.6 V
- Overvoltage switching on switch ports:
  - 0 V to 5 V switching with V<sub>CC</sub> = 2.5 V
  - 0 V to 5 V switching with V<sub>CC</sub> = 3.3 V
- Switch voltage accepts signals up to 5.5 V
- 4 Ω (typical) ON resistance
- 3.5 pF (typical) OFF-state capacitance
- High bandwidth 0.5 GHz (maximum)
- Low input/output capacitance minimizes loading and signal distortion
- Fast switching frequency f<sub>max</sub> = 20 MHz (maximum)
- Low power consumption I<sub>CC</sub> = 0.4 mA (typical)
- Control inputs can be driven by TTL or 5 V/3.3 V CMOS outputs
- · I<sub>OFF</sub> supports partial power-down mode operation
- Latch-up performance exceeds 100 mA per JESD 78E Class II Level A
- ESD protection:
  - HBM ANSI/ESDA/JEDEC JS-001-2012 Class 2 exceeds 2 kV
  - CDM JESD22-C101F exceeds 1000 V
- Specified from -40 °C to +85 °C

### 3. Applications

- Communication infrastructure
- Bus isolation
- Memory interleaving
- Sensor multiplexing



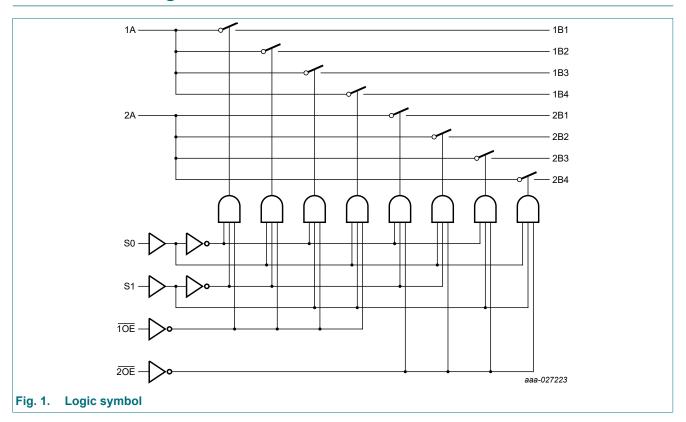
### Dual 1-of-4 FET multiplexer/demultiplexer with charge pump

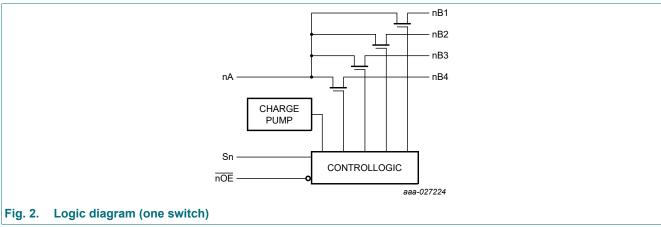
### 4. Ordering information

**Table 1. Ordering information** 

| Type number  | Package           |          |                                                                                                                                |          |  |  |  |  |  |  |
|--------------|-------------------|----------|--------------------------------------------------------------------------------------------------------------------------------|----------|--|--|--|--|--|--|
|              | Temperature range | Name     | Description                                                                                                                    | Version  |  |  |  |  |  |  |
| 74CB3Q3253PW | -40 °C to +85 °C  | TSSOP16  | plastic thin shrink small outline package; 16 leads; body width 4.4 mm                                                         | SOT403-1 |  |  |  |  |  |  |
| 74CB3Q3253BQ | -40 °C to +85 °C  | DHVQFN16 | plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 × 3.5 × 0.85 mm | SOT763-1 |  |  |  |  |  |  |

## 5. Functional diagram

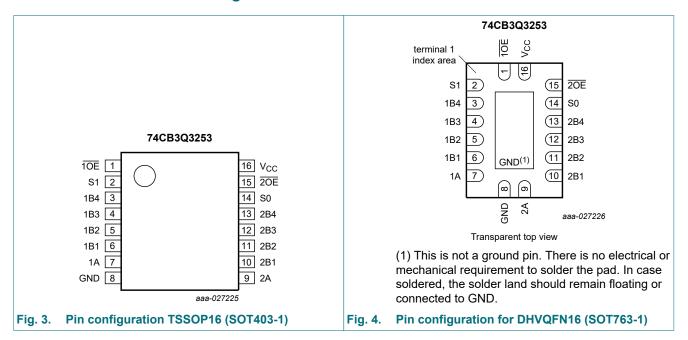




#### Dual 1-of-4 FET multiplexer/demultiplexer with charge pump

### 6. Pinning information

### 6.1. Pinning



### 6.2. Pin description

Table 2. Pin description

| Symbol          | Pin | Description                      |
|-----------------|-----|----------------------------------|
| 10E             | 1   | output enable input (active-LOW) |
| S1              | 2   | select input                     |
| 1B4             | 3   | independent input or output      |
| 1B3             | 4   | independent input or output      |
| 1B2             | 5   | independent input or output      |
| 1B1             | 6   | independent input or output      |
| 1A              | 7   | common output or input           |
| GND             | 8   | ground (0 V)                     |
| 2A              | 9   | common output or input           |
| 2B1             | 10  | independent input or output      |
| 2B2             | 11  | independent input or output      |
| 2B3             | 12  | independent input or output      |
| 2B4             | 13  | independent input or output      |
| S0              | 14  | select input                     |
| 2OE             | 15  | output enable input (active-LOW) |
| V <sub>CC</sub> | 16  | supply voltage                   |

#### Dual 1-of-4 FET multiplexer/demultiplexer with charge pump

### 7. Functional description

#### Table 3. Function table

 $H = HIGH \text{ voltage level}; L = LOW \text{ voltage level}; X = don't care; Z = high-impedance OFF-state.}$ 

| Input |    |   | Channel on     |
|-------|----|---|----------------|
| S1    | S0 |   |                |
| L     | L  | L | nA = nB1       |
| L     | Н  | L | nA = nB2       |
| Н     | L  | L | nA = nB3       |
| Н     | Н  | L | nA = nB4       |
| X     | X  | Н | Z (switch off) |

### 8. Limiting values

#### **Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter               | Conditions                       | Min  | Max  | Unit |
|------------------|-------------------------|----------------------------------|------|------|------|
| V <sub>CC</sub>  | supply voltage          |                                  | -0.5 | +4.6 | V    |
| VI               | input voltage           | Sn, nOE input [1]                | -0.5 | +7.0 | V    |
| V <sub>SW</sub>  | switch voltage          | [2]                              | -0.5 | +7.0 | V    |
| I <sub>IK</sub>  | input clamping current  | V <sub>I</sub> < -0.5 V          | -50  | -    | mA   |
| I <sub>SK</sub>  | switch clamping current | V <sub>I</sub> < -0.5 V          | -50  | -    | mA   |
| I <sub>SW</sub>  | switch current          |                                  | -    | ±120 | mA   |
| I <sub>CC</sub>  | supply current          |                                  | -    | +100 | mA   |
| $I_{GND}$        | ground current          |                                  | -100 | -    | mA   |
| T <sub>stg</sub> | storage temperature     |                                  | -65  | +150 | °C   |
| P <sub>tot</sub> | total power dissipation | $T_{amb}$ = -40 °C to +85 °C [3] | -    | 500  | mW   |

<sup>[1]</sup> The minimum input voltage rating may be exceeded if the input current rating is observed.

### 9. Recommended operating conditions

Table 5. Recommended operating conditions

| Symbol           | Parameter                           | Conditions                       | Min | Max | Unit |
|------------------|-------------------------------------|----------------------------------|-----|-----|------|
| $V_{CC}$         | supply voltage                      |                                  | 2.3 | 3.6 | V    |
| VI               | input voltage                       | Sn, nOE input                    | 0   | 5.5 | V    |
| $V_{SW}$         | switch voltage                      |                                  | 0   | 5.5 | V    |
| T <sub>amb</sub> | ambient temperature                 |                                  | -40 | +85 | °C   |
| Δt/ΔV            | input transition rise and fall rate | Sn, nOE input                    |     |     |      |
|                  |                                     | V <sub>CC</sub> = 2.3 V to 2.7 V | 0   | 20  | ns/V |
|                  |                                     | V <sub>CC</sub> = 2.7 V to 3.6 V | 0   | 10  | ns/V |

<sup>[2]</sup> The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed.

<sup>[3]</sup> For SOT403-1 (TSSOP16) package: P<sub>tot</sub> derates linearly with 8.5 mW/K above 91 °C. For SOT763-1 (DHVQFN16) package: P<sub>tot</sub> derates linearly with 11.2 mW/K above 106 °C.

### Dual 1-of-4 FET multiplexer/demultiplexer with charge pump

### 10. Static characteristics

#### **Table 6. Static characteristics**

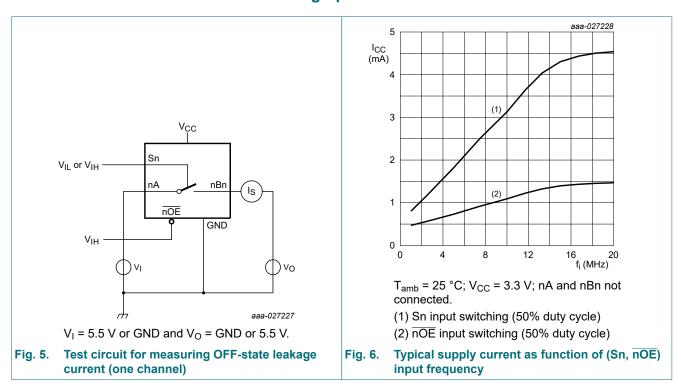
At recommended operating conditions; voltages are referenced to GND (ground 0 V).

| Symbol              | Parameter                    | Conditions                                                                                                      | Ta  | <sub>amb</sub> = 25 | °C  | T <sub>amb</sub> =-40 ° | C to +85 °C | Unit |
|---------------------|------------------------------|-----------------------------------------------------------------------------------------------------------------|-----|---------------------|-----|-------------------------|-------------|------|
|                     |                              |                                                                                                                 | Min | Typ[1]              | Max | Min                     | Max         |      |
| V <sub>IH</sub>     | HIGH-level                   | V <sub>CC</sub> = 2.3 V to 2.7 V                                                                                | -   | -                   | -   | 1.7                     | -           | V    |
|                     | input voltage                | V <sub>CC</sub> = 2.7 V to 3.6 V                                                                                | -   | -                   | -   | 2                       | -           | V    |
| V <sub>IL</sub>     | LOW-level                    | V <sub>CC</sub> = 2.3 V to 2.7 V                                                                                | -   | -                   | -   | -                       | 0.7         | V    |
|                     | input voltage                | V <sub>CC</sub> = 2.7 V to 3.6 V                                                                                | -   | -                   | -   | -                       | 0.8         | V    |
| V <sub>IK</sub>     | input clamping voltage       | nA; nBn; V <sub>CC</sub> = 3.6 V; I <sub>I</sub> = -18 mA                                                       | -   | -                   | -   | -                       | -1.8        | V    |
| I <sub>I</sub>      | input leakage<br>current     | Sn, <del>nOE</del> ; V <sub>CC</sub> = 3.6 V;<br>V <sub>I</sub> = GND to 5.5 V                                  | -   | -                   | -   | -                       | ±1          | μA   |
| l <sub>OFF</sub>    | power-off<br>leakage current | per pin; V <sub>CC</sub> = 0 V;<br>V <sub>SW</sub> or V <sub>I</sub> = 0 V to 5.5 V                             | -   | -                   | -   | -                       | ±1          | μA   |
| I <sub>S(OFF)</sub> | OFF-state<br>leakage current | nA; nBn; V <sub>CC</sub> = 3.6 V; see <u>Fig. 5</u>                                                             | -   | -                   | -   | -                       | ±1          | μΑ   |
| I <sub>CC</sub>     | supply current               | $V_I$ = GND or $V_{CC}$ ; $I_O$ = 0 A;<br>$V_{SW}$ = GND or $V_{CC}$ ; $V_{CC}$ = 3.6 V                         | -   | 0.4                 | -   | -                       | 0.6         | mA   |
| ΔI <sub>CC</sub>    | additional supply current    | Sn, $\overline{\text{nOE}}$ ; V <sub>CC</sub> = 3.6 V; one input at 3 V, other inputs at GND or V <sub>CC</sub> | -   | -                   | -   | -                       | 30          | μA   |
| Cı                  | input<br>capacitance         | V <sub>CC</sub> = 3.3 V; V <sub>SW</sub> = GND or V <sub>CC</sub> ;<br>V <sub>I</sub> = 0 V, 3.3 V, 5.5 V       |     |                     |     |                         |             |      |
|                     |                              | Sn, <del>nOE</del>                                                                                              | -   | 2.5                 | -   | -                       | 3.5         | pF   |
| C <sub>S(OFF)</sub> | OFF-state                    | V <sub>CC</sub> = 3.3 V; V <sub>SW</sub> = 0 V, 3.3 V, 5.5 V                                                    |     |                     |     |                         |             |      |
|                     | capacitance                  | nA                                                                                                              | -   | 8                   | -   | -                       | 11          | pF   |
|                     |                              | nBn                                                                                                             | -   | 3.5                 | -   |                         | 4.5         | pF   |
| C <sub>S(ON)</sub>  | ON-state                     | V <sub>CC</sub> = 3.3 V; V <sub>SW</sub> = 0 V, 3.3 V, 5.5 V                                                    |     |                     |     |                         |             |      |
|                     | capacitance                  | nA, nBn                                                                                                         | -   | 13                  | -   | -                       | 17          | pF   |

<sup>[1]</sup> Typical values are measured at  $V_{CC}$  = 3.3 V unless otherwise specified.

### Dual 1-of-4 FET multiplexer/demultiplexer with charge pump

### 10.1. Test circuit and graph



### Dual 1-of-4 FET multiplexer/demultiplexer with charge pump

### 10.2. ON resistance

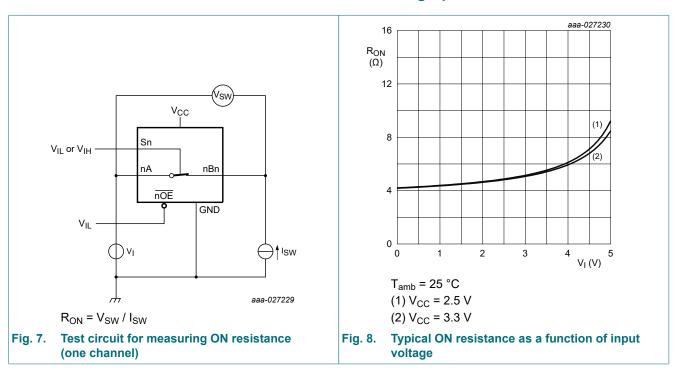
Table 7. ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 7.

| Symbol          | Parameter     | Conditions                                           | Т   | amb = 25 ° | С   | T <sub>amb</sub> = -40 ° | Unit |   |
|-----------------|---------------|------------------------------------------------------|-----|------------|-----|--------------------------|------|---|
|                 |               |                                                      | Min | Тур        | Max | Min                      | Max  |   |
| R <sub>ON</sub> | ON resistance | V <sub>CC</sub> = 2.3 V; see <u>Fig. 8</u>           |     |            |     |                          |      |   |
|                 |               | $V_I = 0 \text{ V}; I_{SW} = 30 \text{ mA}$ [1]      | -   | 4          | -   | -                        | 10   | Ω |
|                 |               | V <sub>I</sub> = 1.7 V; I <sub>SW</sub> = -15 mA [1] | -   | 4.5        | -   | -                        | 11   | Ω |
|                 |               | V <sub>CC</sub> = 3.0 V; see <u>Fig. 8</u>           |     |            |     |                          |      |   |
|                 |               | V <sub>I</sub> = 0 V; I <sub>SW</sub> = 30 mA [2]    | -   | 4          | -   | -                        | 8    | Ω |
|                 |               | V <sub>I</sub> = 2.4 V; I <sub>SW</sub> = -15 mA [2] | -   | 4.8        | -   | -                        | 10   | Ω |

- [1] Typical values are measured at  $V_{CC}$  = 2.5 V.
- [2] Typical values are measured at  $V_{CC}$  = 3.3 V.

### 10.3. ON resistance test circuit and graph



### Dual 1-of-4 FET multiplexer/demultiplexer with charge pump

### 11. Dynamic characteristics

**Table 8. Dynamic characteristics** 

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit, see Fig. 11.

| Symbol           | Parameter    | Conditions                                                                                                                                                         | T <sub>amb</sub> = -40 | °C to +85 °C | Unit |
|------------------|--------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------|--------------|------|
|                  |              |                                                                                                                                                                    | Min                    | Max          |      |
| t <sub>pd</sub>  | propagation  | nA to nBn or nBn to nA; see Fig. 9 [1] [2]                                                                                                                         |                        |              |      |
|                  | delay        | V <sub>CC</sub> = 2.3 V to 2.7 V                                                                                                                                   | -                      | 0.12         | ns   |
|                  |              | V <sub>CC</sub> = 3.0 V to 3.6 V                                                                                                                                   | -                      | 0.2          | ns   |
|                  |              | Sn to nA; see Fig. 9 [1]                                                                                                                                           |                        |              |      |
|                  |              | V <sub>CC</sub> = 2.3 V to 2.7 V                                                                                                                                   | 1.5                    | 6.7          | ns   |
|                  |              | V <sub>CC</sub> = 3.0 V to 3.6 V                                                                                                                                   | 1.5                    | 5.9          | ns   |
| t <sub>en</sub>  | enable time  | nOE to nA, nBn; see Fig. 10 [1]                                                                                                                                    |                        |              |      |
|                  |              | V <sub>CC</sub> = 2.3 V to 2.7 V                                                                                                                                   | 1.5                    | 6.7          | ns   |
|                  |              | V <sub>CC</sub> = 3.0 V to 3.6 V                                                                                                                                   | 1.5                    | 5.9          | ns   |
|                  |              | Sn to nBn; see Fig. 10 [1]                                                                                                                                         |                        |              |      |
|                  |              | V <sub>CC</sub> = 2.3 V to 2.7 V                                                                                                                                   | 1.5                    | 6.7          | ns   |
|                  |              | V <sub>CC</sub> = 3.0 V to 3.6 V                                                                                                                                   | 1.5                    | 5.9          | ns   |
| t <sub>dis</sub> | disable time | nOE to nA, nBn; see Fig. 10 [1]                                                                                                                                    |                        |              |      |
|                  |              | V <sub>CC</sub> = 2.3 V to 2.7 V                                                                                                                                   | 1.0                    | 6.1          | ns   |
|                  |              | V <sub>CC</sub> = 3.0 V to 3.6 V                                                                                                                                   | 1.0                    | 6.1          | ns   |
|                  |              | Sn to nBn; see Fig. 10 [1]                                                                                                                                         |                        |              |      |
|                  |              | V <sub>CC</sub> = 2.3 V to 2.7 V                                                                                                                                   | 1.0                    | 6.1          | ns   |
|                  |              | V <sub>CC</sub> = 3.0 V to 3.6 V                                                                                                                                   | 1.0                    | 6.1          | ns   |
| f <sub>max</sub> | maximum      | Sn, $\overline{\text{nOE}}$ ; $V_{\text{O}} > V_{\text{CC}}$ ; $V_{\text{I}} = 5 \text{ V}$ ; $R_{\text{L}} \ge 1 \text{ M}\Omega$ ; $C_{\text{L}} = 0 \text{ pF}$ |                        |              |      |
|                  | frequency    | V <sub>CC</sub> = 2.3 V to 2.7 V                                                                                                                                   | -                      | 10           | MHz  |
|                  |              | V <sub>CC</sub> = 3.0 V to 3.6 V                                                                                                                                   | -                      | 20           | MHz  |

<sup>[1]</sup>  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

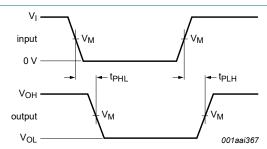
 $t_{\text{en}}$  is the same as  $t_{\text{PZL}}$  and  $t_{\text{PZH}}$ .

 $t_{\text{dis}}$  is the same as  $t_{\text{PLZ}}$  and  $t_{\text{PHZ}}.$ 

<sup>[2]</sup> The propagation delay is the calculated RC time constant of the typical ON resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

### Dual 1-of-4 FET multiplexer/demultiplexer with charge pump

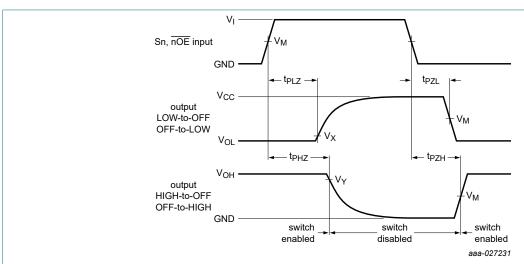
#### 11.1. Waveforms and test circuit



Measurement points are given in Table 9.

Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

Fig. 9. The data input (nA or nBn) to output (nBn or nA) propagation delays



Measurement points are given in Table 9.

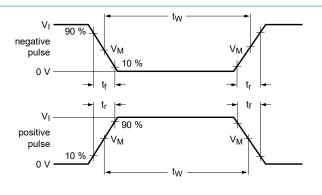
Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

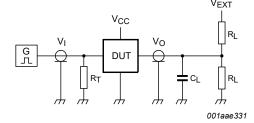
Fig. 10. Enable and disable times

**Table 9. Measurement points** 

| Supply voltage  | Input                 | Output                | Output                   |                          |  |  |  |  |
|-----------------|-----------------------|-----------------------|--------------------------|--------------------------|--|--|--|--|
| V <sub>CC</sub> | V <sub>M</sub>        | V <sub>M</sub>        | V <sub>X</sub>           | V <sub>Y</sub>           |  |  |  |  |
| 2.3 V to 2.7 V  | 0.5 × V <sub>CC</sub> | 0.5 × V <sub>CC</sub> | V <sub>OL</sub> + 0.15 V | V <sub>OH</sub> - 0.15 V |  |  |  |  |
| 3.0 V to 3.6 V  | 0.5 × V <sub>CC</sub> | 0.5 × V <sub>CC</sub> | V <sub>OL</sub> + 0.3 V  | V <sub>OH</sub> - 0.3 V  |  |  |  |  |

### Dual 1-of-4 FET multiplexer/demultiplexer with charge pump





Test data is given in Table 10.

Definitions for test circuit:

 $R_L$  = Load resistance.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to the output impedance  $Z_0$  of the pulse generator.

 $V_{\mathsf{EXT}}$  = External voltage for measuring switching times.

Fig. 11. Test circuit for measuring switching times

Table 10. Test data

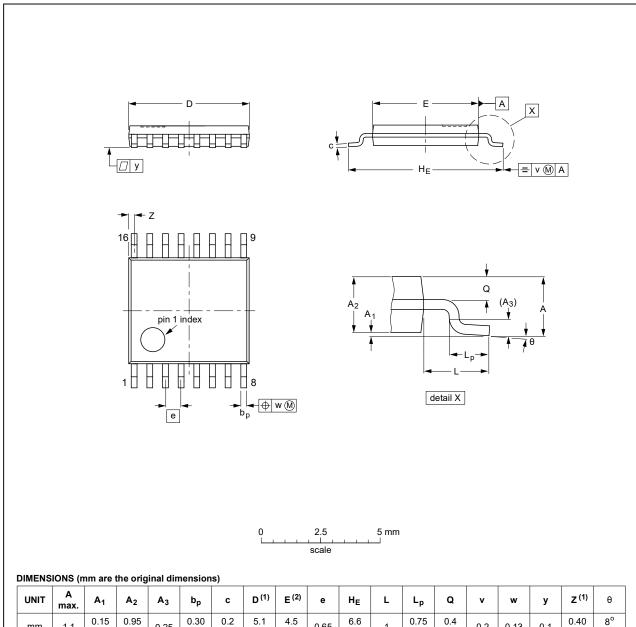
| Supply voltage  |                 |          | Load                          |       | V <sub>EXT</sub>                    |                                     |                                     |  |
|-----------------|-----------------|----------|-------------------------------|-------|-------------------------------------|-------------------------------------|-------------------------------------|--|
| V <sub>CC</sub> |                 |          | C <sub>L</sub> R <sub>L</sub> |       | t <sub>PLH</sub> , t <sub>PHL</sub> | t <sub>PLZ</sub> , t <sub>PZL</sub> | t <sub>PZH</sub> , t <sub>PHZ</sub> |  |
| 2.3 V to 2.7 V  | V <sub>CC</sub> | ≤ 2.5 ns | 30 pF                         | 500 Ω | open                                | 2 × V <sub>CC</sub>                 | GND                                 |  |
| 3.0 V to 3.6 V  | V <sub>CC</sub> | ≤ 2.5 ns | 50 pF                         | 500 Ω | open                                | 2 × V <sub>CC</sub>                 | GND                                 |  |

### Dual 1-of-4 FET multiplexer/demultiplexer with charge pump

### 12. Package outline

#### TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



| UNIT | A<br>max. | A <sub>1</sub> | A <sub>2</sub> | A <sub>3</sub> | b <sub>p</sub> | С          | D <sup>(1)</sup> | E <sup>(2)</sup> | е    | HE         | L | Lp           | Q          | v   | w    | у   | Z <sup>(1)</sup> | θ        |
|------|-----------|----------------|----------------|----------------|----------------|------------|------------------|------------------|------|------------|---|--------------|------------|-----|------|-----|------------------|----------|
| mm   | 1.1       | 0.15<br>0.05   | 0.95<br>0.80   | 0.25           | 0.30<br>0.19   | 0.2<br>0.1 | 5.1<br>4.9       | 4.5<br>4.3       | 0.65 | 6.6<br>6.2 | 1 | 0.75<br>0.50 | 0.4<br>0.3 | 0.2 | 0.13 | 0.1 | 0.40<br>0.06     | 8°<br>0° |

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

| OUTLINE  |     | REFER  | EUROPEAN | ISSUE DATE |            |                                 |  |
|----------|-----|--------|----------|------------|------------|---------------------------------|--|
| VERSION  | IEC | JEDEC  | JEITA    |            | PROJECTION | ISSUE DATE                      |  |
| SOT403-1 |     | MO-153 |          |            |            | <del>99-12-27</del><br>03-02-18 |  |

Fig. 12. Package outline SOT403-1 (TSSOP16)

#### Dual 1-of-4 FET multiplexer/demultiplexer with charge pump

DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

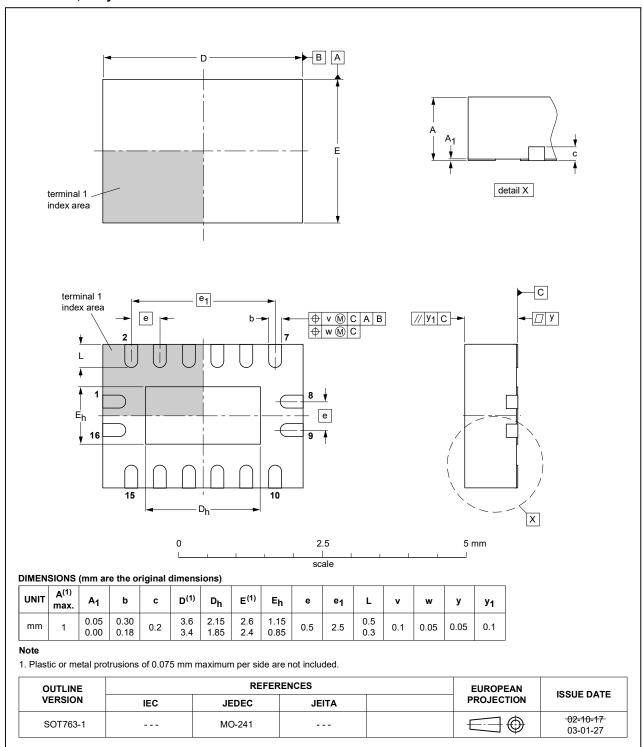


Fig. 13. Package outline SOT763-1 (DHVQFN16)

### Dual 1-of-4 FET multiplexer/demultiplexer with charge pump

### 13. Abbreviations

#### **Table 11. Abbreviations**

| Acronym | Description                             |
|---------|-----------------------------------------|
| CDM     | Charged Device Model                    |
| CMOS    | Complementary Metal Oxide Semiconductor |
| DUT     | Device Under Test                       |
| ESD     | ElectroStatic Discharge                 |
| FET     | Field-Effect Transistor                 |
| НВМ     | Human Body Model                        |
| NMOS    | N-channel Metal-Oxide Semiconductor     |

### 14. Revision history

#### **Table 12. Revision history**

| 1440.0         |              |                                                                                                                                              |               |                |  |  |  |
|----------------|--------------|----------------------------------------------------------------------------------------------------------------------------------------------|---------------|----------------|--|--|--|
| Document ID    | Release date | Data sheet status                                                                                                                            | Change notice | Supersedes     |  |  |  |
| 74CB3Q3253 v.2 | 20210628     | Product data sheet                                                                                                                           | -             | 74CB3Q3253 v.1 |  |  |  |
| Modifications: |              | <ul> <li>Fig. 1: Logic symbol corrected.</li> <li>Section 8: Derating values for P<sub>tot</sub> total power dissipation updated.</li> </ul> |               |                |  |  |  |
| 74CB3Q3253 v.1 | 20170814     | Product data sheet                                                                                                                           | -             | -              |  |  |  |

#### Dual 1-of-4 FET multiplexer/demultiplexer with charge pump

### 15. Legal information

#### **Data sheet status**

| Document status [1][2]         | Product<br>status [3] | Definition                                                                            |
|--------------------------------|-----------------------|---------------------------------------------------------------------------------------|
| Objective [short] data sheet   | Development           | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification         | This document contains data from the preliminary specification.                       |
| Product [short]<br>data sheet  | Production            | This document contains the product specification.                                     |

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### Dual 1-of-4 FET multiplexer/demultiplexer with charge pump

### **Contents**

| 1. General description                     | <i>'</i> |
|--------------------------------------------|----------|
| 2. Features and benefits                   | <i>'</i> |
| 3. Applications                            | 1        |
| 4. Ordering information                    | 2        |
| 5. Functional diagram                      |          |
| 6. Pinning information                     |          |
| 6.1. Pinning                               |          |
| 6.2. Pin description                       |          |
| 7. Functional description                  |          |
| 8. Limiting values                         |          |
| Recommended operating conditions           |          |
| 10. Static characteristics                 |          |
| 10.1. Test circuit and graph               |          |
| 10.2. ON resistance                        |          |
| 10.3. ON resistance test circuit and graph |          |
| 11. Dynamic characteristics                |          |
| 11.1. Waveforms and test circuit           |          |
|                                            |          |
| 12. Package outline                        |          |
| 13. Abbreviations                          |          |
| 14. Revision history                       |          |
| 15. Legal information                      | 14       |
|                                            |          |

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